



PRELIMINARY

SOLID STATE DEVICES, INC

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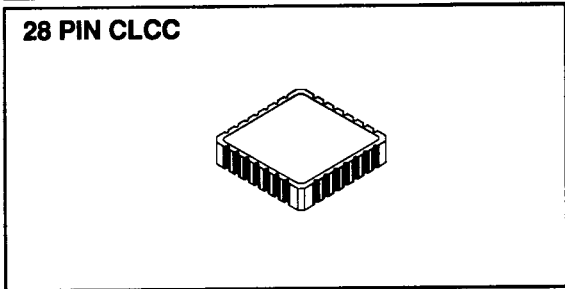
SFF40N10-28

**40* AMP
100 VOLTS
0.055Ω
N-CHANNEL
POWER MOSFET**

Designer's Data Sheet

FEATURES:

- Rugged construction with poly silicon gate
- Low RDS(on) and high transconductance
- Excellent high temperature stability
- Very fast switching speed
- Fast recovery and superior dv/dt performance
- Increased reverse energy capability
- Low input and transfer capacitance for easy paralleling
- Hermetically sealed surface mount package
- TX, TXV and Space Level screening available
- Replaces: SMP40N10 Types



MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	VALUE	UNIT
Drain to Source Voltage	V _{DS}	100	Volts
Gate to Source Voltage	V _{GS}	±20	Volts
Continuous Drain Current	I _D	40*	Amps
Operating and Storage Temperature	Top & Tstg	-55 to +150	°C
Thermal Resistance, Junction to Case	R _{θJC}	2.5	°C/W
Total Device Dissipation @ TC=25°C	P _D	50*	Watts
Total Device Dissipation @ TA=95°C		30	

PACKAGE OUTLINE: 28 PIN CLCC

PIN OUT:
SOURCE: 1, 15- 28
DRAIN: 5-11
GATE: 2, 3, 13, 14

NOTE:
 All Drain/Source Pins must be connected on the PC Board in order to maximize current capability and minimize RDS(on)

Top view dimensions: 0.450 +/- .008 SQ. (square), .040 x 45 CHAM. 3 PLCS. (top chamfer), .020 x 45 CHAM. 1 PLC (bottom chamfer), PIN 26, PIN 1.

Side view dimensions: 0.010 +/- .001 (height), 0.095 MAX. (lead length).

Bottom view dimensions: 0.030 TYP. (lead width), 0.050 TYP. (lead spacing), 0.030 (width), 0.300 (width), 0.035 (width), 0.010 TYP. (width), PIN 1.

* Rating based on size of chip. Device rating may vary depending on mounting and heatsink conditions. Consult SSDI Marketing department for thermal derating details.

NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: F00001 A

MED

SFF40N10-28

PRELIMINARY

SSDI**SOLID STATE DEVICES, INC**14849 Firestone Boulevard · La Mirada, CA 90638
Phone: (714) 670-SSDI (7734) · Fax: (714) 522-7424**ELECTRICAL CHARACTERISTICS @ T_J=25 °C (Unless Otherwise Specified)**

RATING		SYMBOL	MIN	TYP	MAX	UNIT
Drain to Source Breakdown Voltage (V _{GS} =0 V, I _D =250μA)		BV _{DSS}	100	---	---	V
Drain to Source on State Resistance (V _{GS} =10 V, I _D = 25 A)		R _{DS(on)}	---	0.045	0.055**	Ω
On State Drain Current (V _{DS} =5V, V _{GS} =10 V)		I _{D(on)}	40*	---	---	A
Gate Threshold Voltage (V _{DS} =V _{GS} , I _D =250μA)		V _{GS(th)}	2.0	---	4.0	V
Forward Transconductance (V _{DS} =15V, I _{DS} =60% rated I _D)		g _{fs}	10	25	---	S(Ω)
Zero Gate Voltage Drain Current (V _{DS} =80V, V _{GS} =0 V) (V _{DS} =80% rated V _{DS} , V _{GS} =0 V, T _J =125 °C)		I _{DSS}	---	---	25 250	μA
Gate to Source Leakage Forward Gate to Source Leakage Reverse	At rated V _{GS}	I _{GSS}	---	---	100 -100	nA
Total Gate Charge Gate to Source Charge Gate to Drain Charge	V _{GS} =10 Volts 80% rated V _{DS} Rated I _D	Q _g Q _{gs} Q _{gd}	---	60 75 30	120 100 50	nC
Turn on Delay Time Rise Time Turn Off Delay Time Fall Time	T _J =100 °C V _{DD} =25V V _{GEN} =10V I _D =20A R _G =50Ω	t _{d(on)} t _r t _{d(off)} t _f	---	17 80 40 20	50 300 150 100	nsec
Diode Forward Voltage (I _S =rated I _D , V _{GS} =0 V, T _J =25 °C)		V _{SD}	---	1	2	V
Diode Reverse Recovery Time Reverse Recovery Charge	T _J =25 °C I _F =rated I _D di/dt=100 A/ sec	t _{rr} Q _{RR}	---	120 0.3	250 ---	nsec μC
Input Capacitance Output Capacitance Reverse Transfer Capacitance	V _{GS} =0 Volts V _{DS} =25 Volts f= 1 MHz	C _{iss} C _{oss} C _{rss}	---	3000 750 150	5000 2500 1000	pF

For thermal derating curves and other characteristic curves please contact SSDI Marketing Department.

NOTES:

- * Rating based on size of chip. Device rating may vary depending on mounting and heatsink conditions. Consult SSDI Marketing department for thermal derating details.
- ** Due to package resistance; all Source/Drain pins must be connected on the PC Board in order to obtain the lowest R_{DS(on)} possible.